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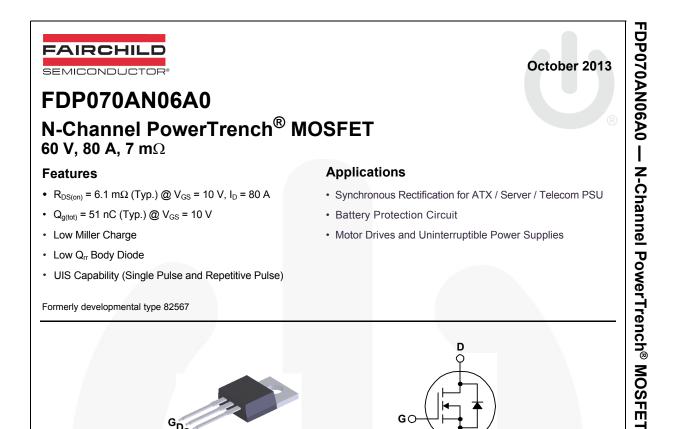


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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TO-220

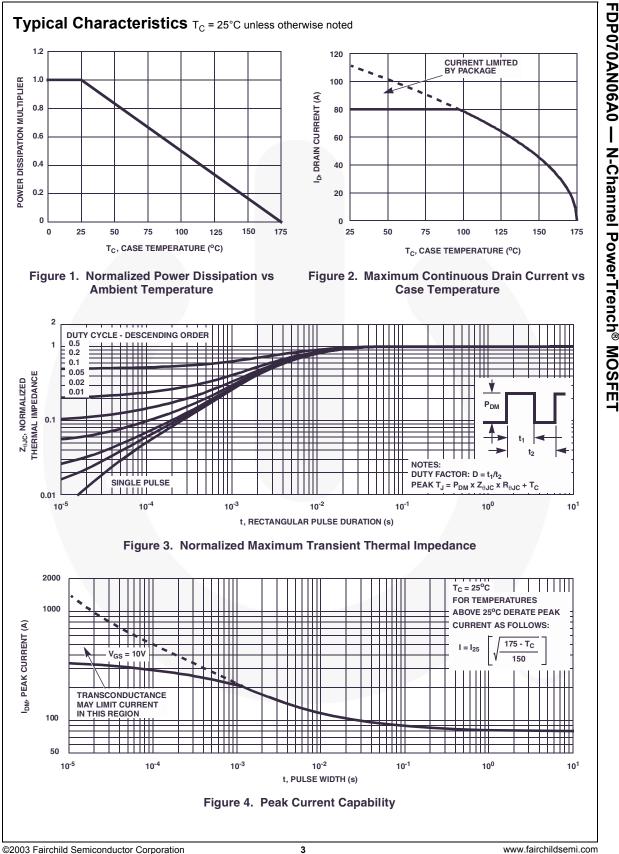
Symbol	Parameter	FDP070AN06A0	Unit
V _{DSS}	Drain to Source Voltage	60	V
V _{DSS} V _{GS}	Gate to Source Voltage	±20	V
	Drain Current		
I _D	Continuous ($T_C < 97^{\circ}C$, $V_{GS} = 10V$)	80	А
	Pulsed	Figure 4	А
E _{AS}	Single Pulse Avalanche Energy (Note 1)	190	mJ
	Power dissipation	175	W
P _D	Derate above 25°C	1.17	W/ ^o C
T _J , T _{STG}	Operating and Storage Temperature	-55 to 175	°C

Thermal Characteristics

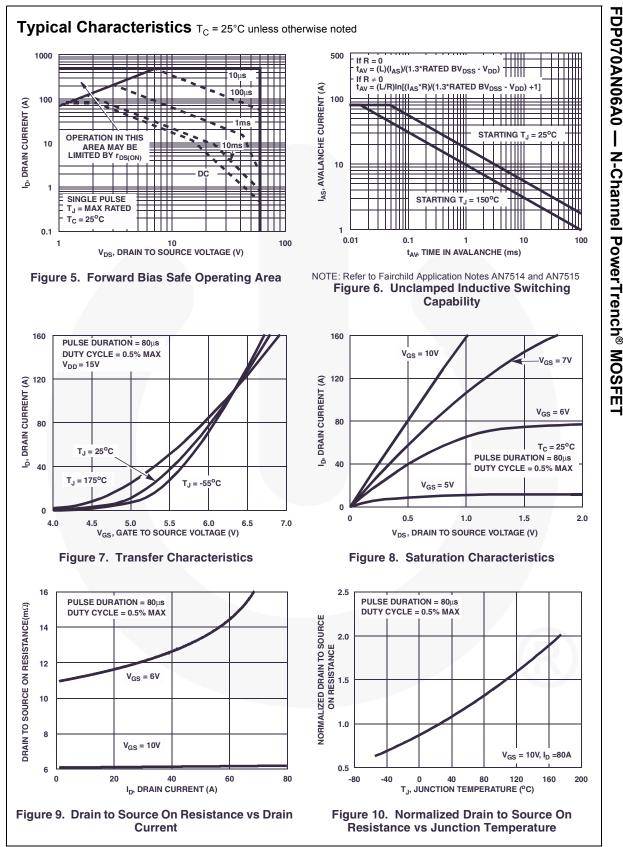
$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case, Max.	0.86	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient, Max. (Note 2)	62	°C/W

Device	Marking	Device Package Reel Size		Reel Size	Tape \	Nidth	Quar	ntity
FDP070AN06A0		FDP070AN06A0	TO-220 N/A		N/A		50 units	
Electric	al Chara	acteristics T _c = 25°0	C unless otherw	ise noted.				
Symbol		Parameter	Test Conditions		Min	Тур	Max	Unit
Off Chara	cteristics	6						
B _{VDSS}	Drain to Source Breakdown Voltage		I _D = 250μA,	V _{GS} = 0V	60	-	-	V
	Zero Gate	-	V _{DS} = 50V		-	-	1	ıιΔ
I _{DSS}	Zero Gate Voltage Drain Current		V _{GS} = 0V	T _C = 150 ^o C	-	-	250	μA
I _{GSS}	Gate to Sc	ource Leakage Current	V _{GS} = ±20V		-	-	±100	nA
On Chara	cteristics	5						
V _{GS(TH)}		ource Threshold Voltage	V _{GS} = V _{DS} ,	I _D = 250μA	2	-	4	V
			I _D = 80A, V ₀	_{es} = 10V	-	0.0061	0.007	
r _{DS(ON)}	Drain to So	ource On Resistance	$I_D = 80A, V_{GS} = 10V,$ $T_J = 175^{\circ}C$		-	0.0127	0.015	Ω
Dynamic	Characte	ristics						
C _{ISS}	Input Capa				-	3000	_	pF
C _{OSS}	Output Ca		V _{DS} = 25V, 1 f = 1MHz	$V_{GS} = 0V,$	-	510	-	pF
C _{RSS}	Reverse Ti	ansfer Capacitance			-	230	-	pF
Q _{g(TOT)}	Total Gate	Charge at 10V	V _{GS} = 0V to	10V		51	66	nC
Q _{g(TH)}	Threshold	Gate Charge	V _{GS} = 0V to	2V V _{DD} = 30V	-	5.4	7	nC
Q _{gs}	Gate to Sc	ource Gate Charge		I _D = 80A	-	17	-	nC
Q _{gs2}	Gate Char	ge Threshold to Plateau		I _g = 1.0mA	-	11.6	-	nC
Q _{gd}	Gate to Dr	ain "Miller" Charge			-	16	-	nC
Switching	g Charact	eristics (V _{GS} = 10V)						
t _{ON}	Turn-On T	ime			-	-	256	ns
t _{d(ON)}	Turn-On D	elay Time			-	12	-	ns
t _r	Rise Time		V _{DD} = 30V, I	_D = 80A	-	159	-	ns
t _{d(OFF)}	Turn-Off D	elay Time	V _{GS} = 10V,	R _{GS} = 5.6Ω	-	27	-	ns
t _f	Fall Time				-	35	-	ns
t _{OFF}	Turn-Off T	ime			-	-	93	ns
Drain-Sou	urce Diod	e Characteristics						
V.	Source to	Course to Durin Diada Maltana			-	-	1.25	V
V _{SD}	Source to Drain Diode Voltage	I _{SD} = 80A I _{SD} = 40A		- /	-	1.0	V	
t _{rr}		ecovery Time		I _{SD} /dt = 100A/μs		-	34	ns
Q _{RR}	Reverse R	ecovered Charge	I_{SD} = 75A, dI_{SD}/dt = 100A/µs		-	-	35	nC

FDP070AN06A0 — N-Channel PowerTrench® MOSFET

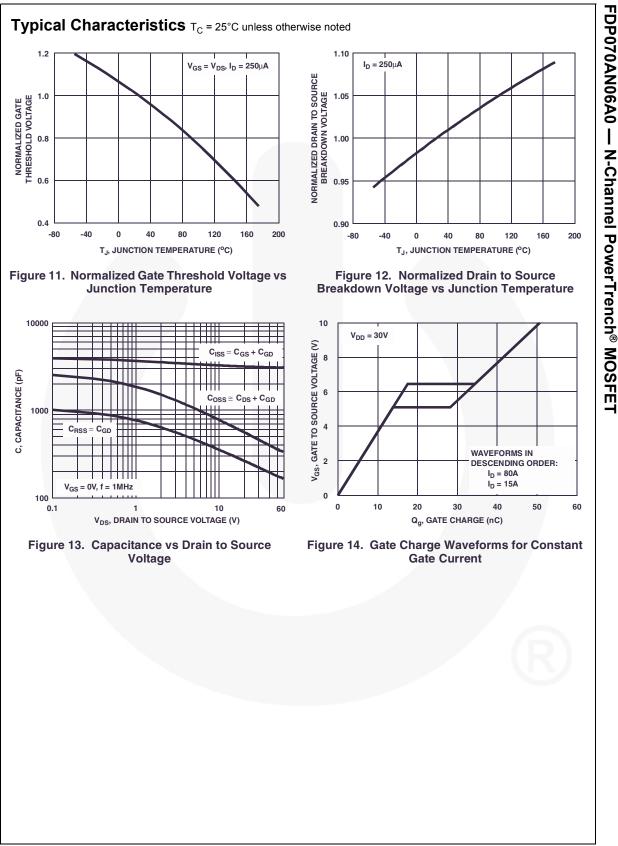


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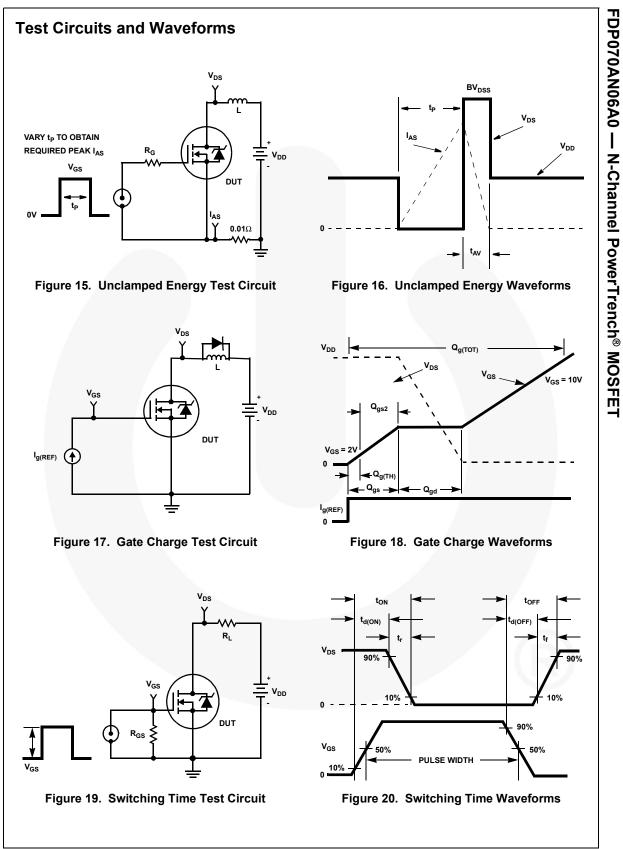


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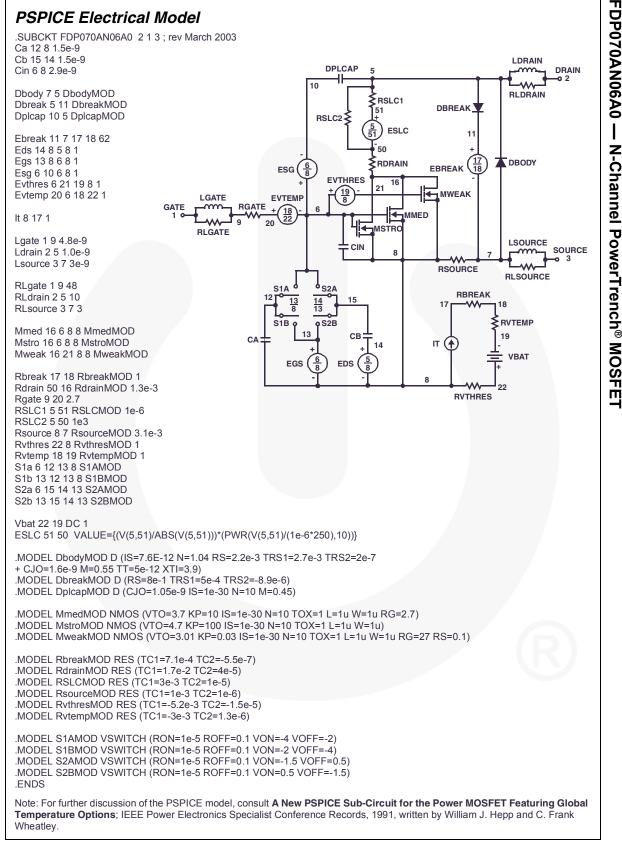
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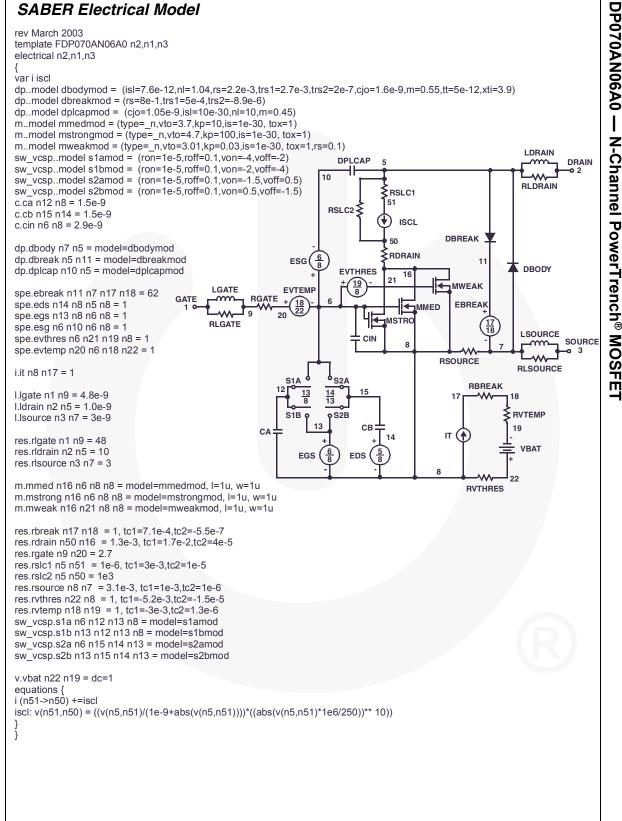
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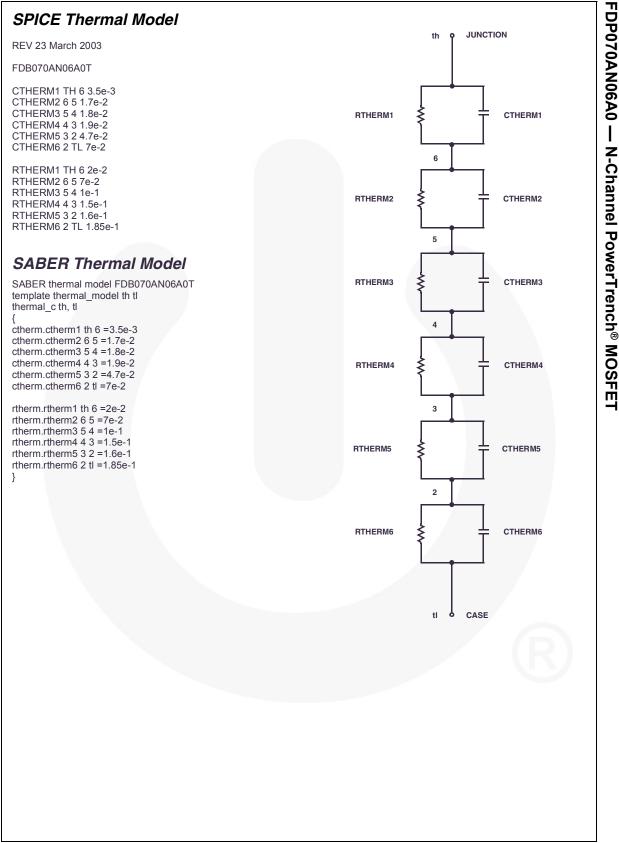


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SABER Electrical Model





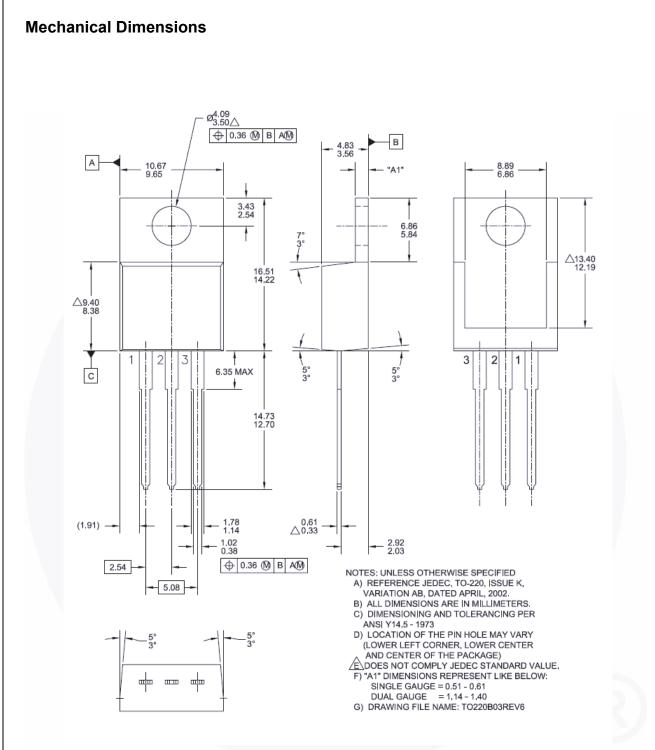


Figure 21. TO-220, Molded, 3-Lead, Jedec Variation AB

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N-Channel PowerTrench® MOSFET

Obsolete

Not In Production

Datasheet contains specifications on a product that is discontinued by Fairchild

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